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30V, N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD17553Q5A

FEATURES

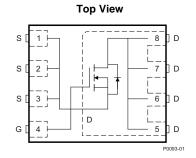
- Ultralow Q_g and Q_{gd}
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5-mm × 6-mm Plastic Package

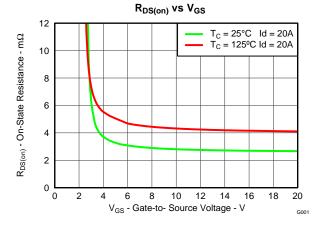
APPLICATIONS

- Point of load Synchronous Buck in Networking, Telecom and Computing Systems
- Optimized for Control and Synchronous FET Applications

DESCRIPTION

The NexFET power MOSFET has been designed to minimize losses in power conversion applications.





PRODUCT SUMMARY

V _{DS}	Drain to Source Voltage	30	V	
Qg	Gate Charge Total (4.5V)	17.5	nC	
Q _{gd}	Gate Charge Gate to Drain	4.7	nC	
	Drain to Source On Desistance	$V_{GS} = 4.5V$	3.5	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V 2.7		mΩ
V _{GS(th)}	Threshold Voltage	1.5	V	

ORDERING INFORMATION

Device	Package	Media	Qty	Ship	
CSD17553Q5A	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel	

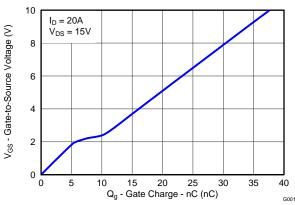
ABSOLUTE MAXIMUM RATINGS

T _A = 2	5°C unless otherwise stated	VALUE	UNIT					
V_{DS}	Drain to Source Voltage	30	V					
V_{GS}	Gate to Source Voltage	+/-20	V					
	Continuous Drain Current, $T_C = 25^{\circ}C$	100	А					
I _D	Continuous Drain Current, $T_A = 25^{\circ}C^{(1)}$	23.5	А					
I _{DM}	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$	151	А					
PD	Power Dissipation ⁽¹⁾	3.1	W					
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C					
E _{AS}	Avalanche Energy, Single Pulse I _D = 45A, L = 0.1mH, R _G = 25Ω	101	mJ					

(1) Typical $R_{\theta JA} = 40.5^{\circ}$ C/W on a 1-inch² (6.45-cm²),

2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.

(2) Pulse duration \leq 300µs, duty cycle \leq 2%



GATE CHARGE



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SLPS373-MAY 2012

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN TYP	MAX	UNIT
Static Ch	haracteristics				
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	30		V
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 24V$		1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = 20V$		100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1 1.5	1.9	V
D	Drain to Source On Registeres	$V_{GS} = 4.5V, I_D = 20A$	3.5	4	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 10V, I_D = 20A$	2.7	3.1	mΩ
9 _{fs}	Transconductance	$V_{DS} = 15V, I_{D} = 20A$	106		S
Dynamic	c Characteristics				
C _{iss}	Input Capacitance		2710	3252	pF
Coss	Output Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$ f = 1MHz	635	762	pF
C _{rss}	Reverse Transfer Capacitance		48	60	pF
R_{G}	Series Gate Resistance		0.7	0.9	Ω
Qg	Gate Charge Total (4.5V)		17.5	21.5	nC
Q _{gd}	Gate Charge Gate to Drain)/ _ 15)/ _ 200	4.7		nC
Q _{gs}	Gate Charge Gate to Source	$V_{DS} = 15V, I_D = 20A$	5.8		nC
Q _{g(th)}	Gate Charge at Vth		4.1		nC
Q _{oss}	Output Charge	$V_{DS} = 15V, V_{GS} = 0V$	19.6		nC
t _{d(on)}	Turn On Delay Time		9.7		ns
t _r	Rise Time	V _{DS} = 15V, V _{GS} = 4.5V,	17		ns
t _{d(off)}	Turn Off Delay Time	$I_{DS} = 20A, R_G = 0.75\Omega$	14.8		ns
t _f	Fall Time		5.2		ns
Diode Cl	haracteristics				
V_{SD}	Diode Forward Voltage	$I_{DS} = 20A, V_{GS} = 0V$	0.8	1	V
Q _{rr}	Reverse Recovery Charge	1/1 = 14/1 = 200 di/dt = 2000//::0	23.8		nC
t _{rr}	Reverse Recovery Time	V_{DS} = 14V, I _F = 20A, di/dt = 300A/µs	23.1		ns

THERMAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	MIN	TYP	MAX	UNIT
$R_{ extsf{ heta}JC}$	Thermal Resistance Junction to Case ⁽¹⁾			1.3	°C/W
R_{\thetaJA}	Thermal Resistance Junction to Ambient ⁽¹⁾⁽²⁾			50.6	°C/W

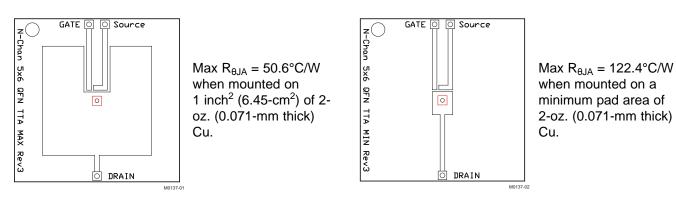
 $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch x 1.5-inch (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu. (1)

(2)



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TYPICAL MOSFET CHARACTERISTICS

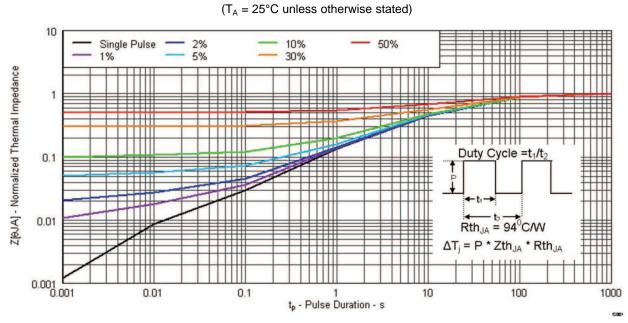


Figure 1. Transient Thermal Impedance

SLPS373-MAY 2012

TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

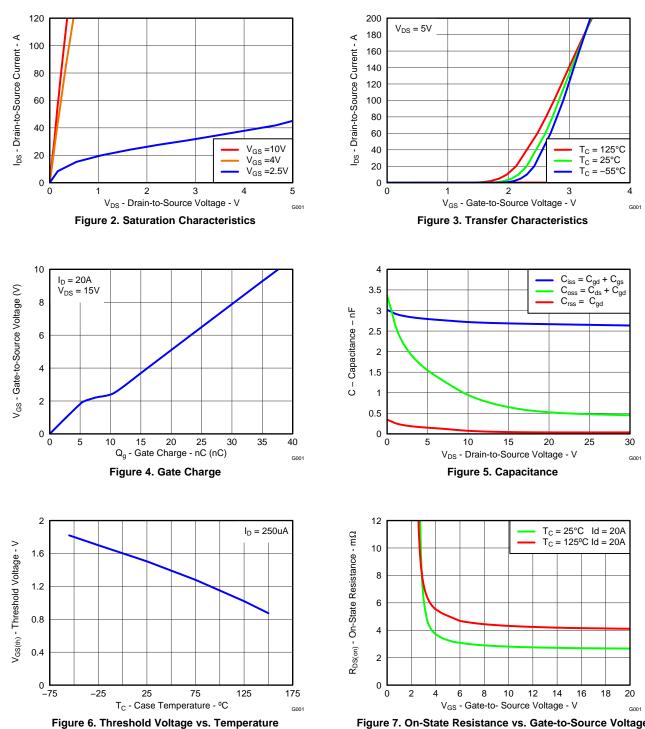


Figure 7. On-State Resistance vs. Gate-to-Source Voltage

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TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

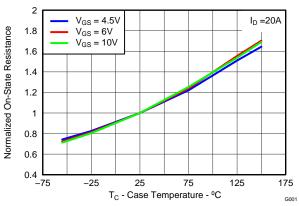


Figure 8. Normalized On-State Resistance vs. Temperature

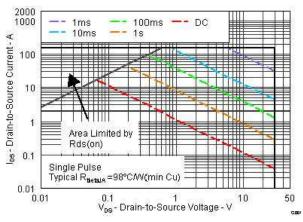


Figure 10. Maximum Safe Operating Area

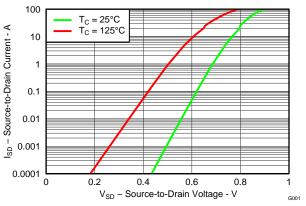


Figure 9. Typical Diode Forward Voltage

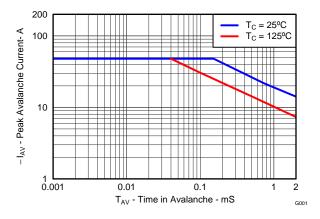
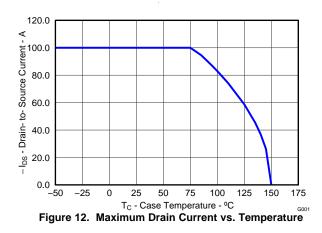


Figure 11. Single Pulse Unclamped Inductive Switching

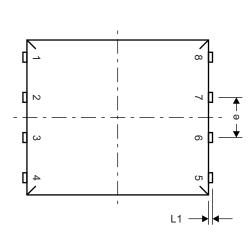


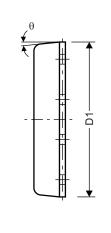
TEXAS INSTRUMENTS

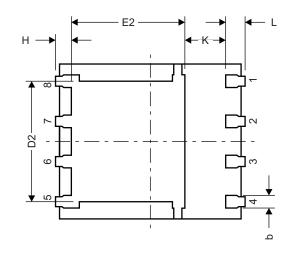
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MECHANICAL DATA

Q5A Package Dimensions



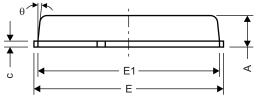




Top View

Side View

Bottom View



Front View

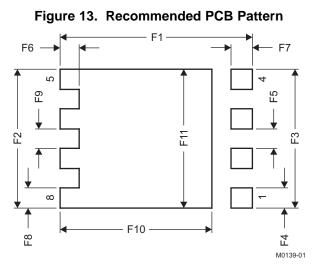
M0135-01

DIM	MILLIMETERS					
DIM	MIN	NOM	MAX			
А	0.90	1.00	1.10			
b	0.33	0.41	0.51			
С	0.20	0.25	0.34			
D1	4.80	4.90	5.00			
D2	3.61	3.81	4.02			
E	5.90	6.00	6.10			
E1	5.70	5.75	5.80			
E2	3.38	3.58	3.78			
е	1.17	1.27	1.37			
Н	0.41	0.56	0.71			
К	1.10					
L	0.51	0.61	0.71			
L1	0.06	0.13	0.20			
θ	0°		12°			



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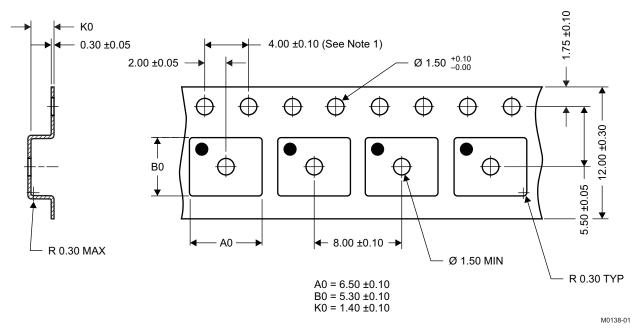




MIN			
	MAX	MIN	MAX
6.205	6.305	0.244	0.248
4.46	4.56	0.176	0.18
4.46	4.56	0.176	0.18
0.65	0.7	0.026	0.028
0.62	0.67	0.024	0.026
0.63	0.68	0.025	0.027
0.7	0.8	0.028	0.031
0.65	0.7	0.026	0.028
0.62	0.67	0.024	0.026
4.9	5	0.193	0.197
4.46	4.56	0.176	0.18
	4.46 4.46 0.65 0.62 0.63 0.7 0.65 0.62 4.9	4.46 4.56 4.46 4.56 0.65 0.7 0.62 0.67 0.63 0.68 0.7 0.8 0.65 0.7 0.62 0.67 4.9 5	4.46 4.56 0.176 4.46 4.56 0.176 0.65 0.7 0.026 0.62 0.67 0.024 0.63 0.68 0.025 0.7 0.8 0.028 0.65 0.7 0.026 0.63 0.68 0.025 0.7 0.8 0.028 0.65 0.7 0.026 0.62 0.67 0.024 4.9 5 0.193

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

Q5A Tape and Reel Information



Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket



PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
CSD17553Q5A	Active	Production	VSONP (DQJ) 8	2500 LARGE T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	CSD17553
CSD17553Q5A.B	Active	Production	VSONP (DQJ) 8	2500 LARGE T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	CSD17553

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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